

EAST Search History

EAST Search History (Prior Art)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	63	("20010044259" "20020006558" "20020056838" "20020056838" "20020104995" "20030059717" "20030127974" "20030165714" "20030168966" "20030210361" "20040005739" "20040005739" "20040065345" "20040160167" "20040216324" "20050026423" "20050026423" "20050037614" "20050037614" "20050088106" "20070069210" "20070146568" "20100019242" "20100090223" "5084905" "5747930" "6346730" "6614053" "6614053" "6639265" "6709902" "6767772" "6767772" "6994414" "7119365" "7136127" "7176068" "7198816" "7619250" "7638846"). PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/08/15 15:14
L5	3701	445/24.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/08/15 15:18
L6	7	(display and device and droplet and planarization) and 5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/08/15 15:19

S2	13	("20020056838" "20020056838" "20040005739" "20040005739" "20050026423" "20050026423" "20050037614" "20050037614" "5747930" "6614053" "6614053" "6767772" "6767772").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 18:46
S3	3864	(display and (drain with gate with connect\$3)).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 18:48
S4	559	S3 and ((electron and hole) near2 (inject\$3 transport \$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 18:49
S5	374	S3 and ((electron with hole) near2 (inject\$3 with transport\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 18:50
S7	111	(organic near2 (el electro electroluminescen\$2)).clm. and (nitrogen with (insulation insulating planarization defining spacer))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 19:32
S9	2	(organic near2 (el electro electroluminescen\$2)).clm. and ((protect\$3) with (scan and signal) with line)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 19:41
S10	10	(organic near2 (el electro electroluminescen\$2)).clm. and ((protect\$3 adj circuit) with (scan signal))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 19:42
S11	866	(organic near2 (el electro electroluminescen\$2)).clm. and ((droplet ink) near2 method)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 19:48

S12	165	(organic near2 (el electro electroluminescen\$2)).clm. and ((droplet ink) near2 method) and (mask\$3 same etch\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 19:48
S14	88	(organic near2 (el electro electroluminescen\$2)).clm. and (droplet near2 discharge)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 19:53
S16	6	(organic near2 (el electro electroluminescen\$2)).clm. and (treat\$3 with photocatalyst)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 19:58
S17	165	(organic near2 (el electro electroluminescen\$2)).clm. and ((remov\$3 clean\$3) with (organic) with water)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 20:19
S19	0	(organic near2 (el electro electroluminescen\$2)).clm. and (planariz\$3 with spray \$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 20:38
S20	16	(planariz\$3 with spray\$3 with gas)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 20:38
S21	2	"5747930".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 20:47
S22	2020	((droplet (ink near2 jet) inkjet) near3 method) and planariz\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 20:54
S23	394	((droplet (ink near2 jet) inkjet) near3 (method process)) and (planariz\$3 with process)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 20:55
S24	70	S23 and @pd<"20031114"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/04/12 20:55

S25	1	10/576495	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/29 23:24
S26	8025	(organic near2 (el electro electroluminescen\$2)).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/29 23:26
S27	8517	313/504,506.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/29 23:28
S28	13018	S26 S27	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/29 23:28
S29	40	S28 and ((photocatalyst (photo near2 catalyst)) with substrate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/29 23:29
S31	26	S28 and ((photocatalyst (photo near2 catalyst)) with (treat treatment pretreat pretreatment))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/29 23:31
S33	13300	313/498-512.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/29 23:34
S34	17462	S26 S33	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/29 23:34
S35	27	S34 and ((photocatalyst (photo near2 catalyst)) with (treat treatment pretreat pretreatment))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/29 23:34
S37	171	((photocatalyst (photo near2 catalyst)) with (treat treatment pretreat pretreatment) with substrate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/29 23:35

S39	2	((photocatalyst (photo near2 catalyst)) with (treat treatment pretreat pretreatment) with substrate with ((ink near2 jet) droplet))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/29 23:37
S40	180	((photocatalyst (photo near2 catalyst)) with substrate with (transistor tft gate electrode))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/29 23:51
S41	26	S34 and S40	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/29 23:52
S43	14	((photocatalyst (photo near2 catalyst)) with substrate with (pretreat pretreatment treat treatment) with (adhesivity adhesion))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/29 23:56
S44	182	((photocatalyst (photo near2 catalyst)) with substrate with (adhesivity adhesion))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/30 00:12
S45	168	S44 not S43	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/30 00:12
S47	410	(gate near2 electrode) with (convex concave curved semicircular) with shape	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/30 00:53
S48	8	S34 and S47	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/30 00:53
S51	220994	(electrode with (liquid ink droplet))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/30 01:10

S52	216882	(electrode with (liquid ink))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/30 01:10
S53	2008	S34 and S52	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/10/30 01:11

EAST Search History (Interference)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	6	(display and device and gate and electrode and thickness and decreases and continuously).clm.	US-PGPUB; USPAT; UPAD	OR	ON	2010/08/15 15:15
L3	1	(display and device and columnar and conductive and droplet and planarization).clm.	US-PGPUB; USPAT; UPAD	OR	ON	2010/08/15 15:16
L4	10	(display and device and droplet and planarization).clm.	US-PGPUB; USPAT; UPAD	OR	ON	2010/08/15 15:17

8/15/2010 3:19:18 PM

C:\Documents and Settings\bwon\My Documents\EAST\Workspaces\10576495-20090411.wsp